## PHOTONIC DETECTORS INC.

## Silicon Photodiode, Blue Enhanced Photoconductive

PACKAGE DIMENSIONS INCH [mm]


FEATURES

- High speed
- Low capacitance
- Blueenhanced
- Low dark current


## DESCRIPTION

The PDB-C207 is a silicon, pin planar diffused, blue enhanced quadrant photodiode. Ideal for high speed photoconductive applications. Packaged in a hermetic TO-46 metal can with a flat window.

## APPLICATIONS

- Optical alignment
- Position sensing
- Edge sensing
- Instrumentation

ABSOLUTE MAXIMUM RATING (TA $=25^{\circ} \mathrm{C}$ unless otherwise noted)

| SYMBOL | PARAMETER | MIN | MAX | UNITS |
| :---: | :--- | :---: | :---: | :---: |
| $\mathrm{V}_{\text {BR }}$ | Reverse Voltage |  | 100 | V |
| $\mathrm{~T}_{\text {STG }}$ | Storage Temperature | -30 | +100 | ${ }^{\circ} \mathrm{C}$ |
| T | Operating Temperature Range | -20 | +80 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{s}}$ | Soldering Temperature ${ }^{*}$ |  | +240 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{I}_{\mathrm{L}}$ | Light Current |  | 0.5 | mA |

*1/16 inch from case for 3 secs max

SPECTRALRESPONSE


WAVELENGTH (nm)

ELECTRO-OPTICAL CHARACTERISTICS (TA $=25^{\circ} \mathrm{C}$ unless otherwise noted)

| SYMBOL | CHARACTERISTIC | TESTCONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :--- | :--- | :---: | :---: | :---: | :---: |
| Isc | Short Circuit Current | $\mathrm{H}=100 \mathrm{fc}, 2850 \mathrm{~K}$ | 1.5 | 2.2 |  | $\mu \mathrm{~A}$ |
| ID | Dark Current | $\mathrm{H}=0, \mathrm{~V}_{\mathrm{R}}=1 \mathrm{~V}$ |  | 1 | 5 | nA |
| Rsh | Shunt Resistance | $\mathrm{H}=0, \mathrm{~V}_{\mathrm{R}}=10 \mathrm{mV}$ | 100 | 500 |  | $\mathrm{M} \Omega$ |
| TC Rsh | Rsh Temp. Coefficient | $\mathrm{H}=0, \mathrm{~V}_{\mathrm{R}}=10 \mathrm{mV}$ |  | -8 |  | $\% /{ }^{\circ} \mathrm{C}$ |
| $\mathrm{C}_{J}$ | Junction Capacitance | $\mathrm{H}=0, \mathrm{~V}_{\mathrm{R}}=10 \mathrm{~V}$ |  | 10 |  | pF |
| $\lambda_{\text {range }}$ | Spectral Application Range | Spot Scan | 350 |  | 1100 | nm |
| $\lambda_{\mathrm{p}}$ | Spectral Response - Peak | Spot Scan |  | 950 |  | nm |
| $\mathrm{~V}_{\mathrm{BR}}$ | Breakdown Voltage | $\mathrm{I}=10 \mu \mathrm{~A}$ | 30 | 75 |  | V |
| NEP | Noise Equivalent Power | $\mathrm{V}_{\mathrm{R}}=10 \mathrm{~V} @$ Peak |  | $6 \times 10^{-13}$ |  | $\mathrm{~W} / \sqrt{\mathrm{Hz}}$ |
| tr | Response Time | $\mathrm{RL}=1 \mathrm{~K} \Omega \mathrm{~V}_{\mathrm{R}}=10 \mathrm{~V}$ |  | 100 |  | nS |

Information in this technical data sheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice.

